

Exam Summer Semester 2022

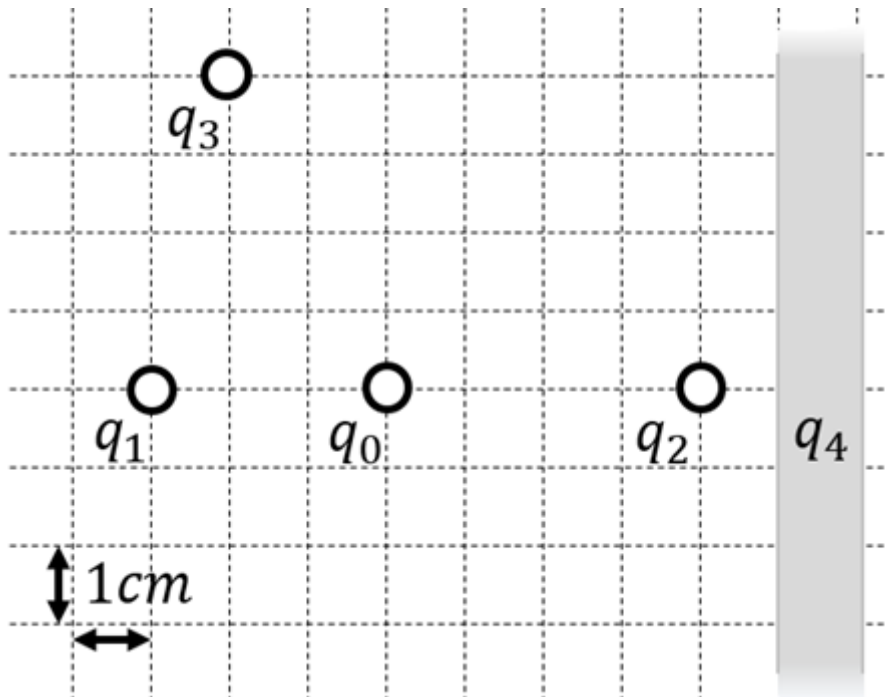
Student Group

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1. Calculate the single forces $\vec{F}_{01}$, $\vec{F}_{02}$, $\vec{F}_{03}$, on the charge q_0 !

Path

First, calculate the magnitude of the forces, like $\vec{F}_{01}$.

The force $\vec{F}_{01}$ is purely on the x -axis and therefore equal to

$$\begin{aligned} F_{01,x} &= \frac{1}{4\pi\epsilon_0} \cdot \frac{q_1 \cdot q_0}{r_{01}^2} = \\ &= \frac{1}{4\pi \cdot 8.854 \cdot 10^{-12} \text{ As/Vm}} \cdot \frac{1 \cdot 10^{-9} \text{ C} \cdot 2 \cdot 10^{-9} \text{ C}}{(3 \cdot 10^{-2} \text{ m})^2} = 19.97... \cdot 10^{-6} \text{ Nm} \\ &= 19.97... \cdot 10^{-6} \text{ Nm} \quad \text{(to the right)} \end{aligned}$$

Similarly, we get for $\vec{F}_{02}$ and $\vec{F}_{03}$

$$\begin{aligned} \vec{F}_{02} &= F_{02,x} = -28.09... \text{ Nm} \quad \text{(to the right)} \\ \vec{F}_{03} &= -22.47... \text{ Nm} \quad \text{(to the top left)} \end{aligned}$$

For $\vec{F}_{03}$, we have to calculate the x - and y -component.

This is possible, by using the angle α between the line through q_0 and q_3 and the positive x -axis (pointing to the right).

So, α has to be between 90° and 180° . It can be calculated by:

$$\begin{aligned} \alpha &= \arctan\left(\frac{-4 \text{ cm}}{+2 \text{ cm}}\right) = \pi - 1.1071... \\ &= 180^\circ - 63.4...^\circ = 116.6...^\circ \end{aligned}$$

Based on this, the x - and y -component is:

$$\begin{aligned} |\vec{F}_{03}| \cdot \cos \alpha &= 10.05... \text{ Nm} \quad \text{(to the left)} \\ F_{03,y} &= |\vec{F}_{03}| \cdot \sin \alpha = 20.10... \text{ Nm} \quad \text{(to the top)} \end{aligned}$$

top}} \end{align*}

Exercise E2 Electrostatics I

(written test, approx. 10 % of a 120-minute written test, SS2022)

2. What is the magnitude of the electric force on the charge q_0 ? The picture below shows the values of the point charges q_1, q_2, q_3 and q_4 . Which value needs E_4 to have to get a resulting force of 0 N on q_0 ?

Path:

- $q_0 = -1 \text{ nC}$

- $q_1 = -2 \text{ nC}$

Path: $E_4 = 2310.97 \text{ V/m}$

- $\vec{F}_1 = \left(\begin{array}{c} 19.97 \\ 0 \\ 0 \end{array} \right) \text{ nN}$

With the given data and the position of the charges, we cannot calculate the resulting magnitude of the force on q_0 .

The potential difference between the position $\vec{r}_0 = 8.854 \cdot 10^{-12} \text{ m}$ and $\vec{r}_1 = 1 \text{ m}$ is

$$V_1 = \frac{1}{4\pi\epsilon_0} \frac{q_1}{r_1} = \frac{1}{4\pi \cdot 8.854 \cdot 10^{-12} \text{ F/m}} \frac{-2 \cdot 10^{-9} \text{ C}}{1 \text{ m}} = -4.5 \cdot 10^{-2} \text{ V}$$

$$V_2 = \frac{1}{4\pi\epsilon_0} \frac{q_2}{r_2} = \frac{1}{4\pi \cdot 8.854 \cdot 10^{-12} \text{ F/m}} \frac{-2 \cdot 10^{-9} \text{ C}}{1 \text{ m}} = -4.5 \cdot 10^{-2} \text{ V}$$

$$V_3 = \frac{1}{4\pi\epsilon_0} \frac{q_3}{r_3} = \frac{1}{4\pi \cdot 8.854 \cdot 10^{-12} \text{ F/m}} \frac{-2 \cdot 10^{-9} \text{ C}}{1 \text{ m}} = -4.5 \cdot 10^{-2} \text{ V}$$

$$V_4 = \frac{1}{4\pi\epsilon_0} \frac{q_4}{r_4} = \frac{1}{4\pi \cdot 8.854 \cdot 10^{-12} \text{ F/m}} \frac{-2 \cdot 10^{-9} \text{ C}}{1 \text{ m}} = -4.5 \cdot 10^{-2} \text{ V}$$

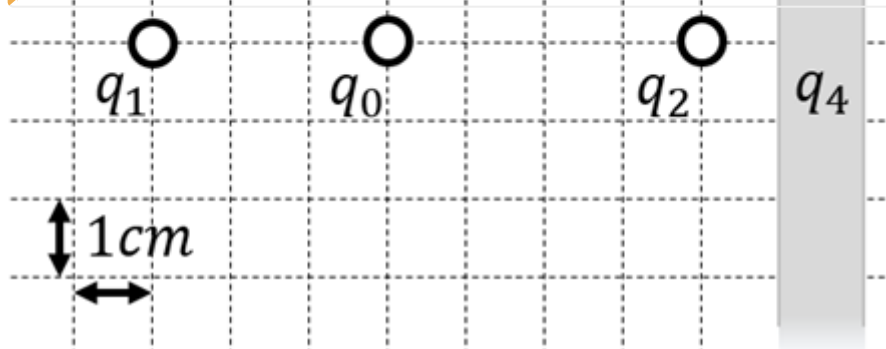
$$V_5 = \frac{1}{4\pi\epsilon_0} \frac{q_5}{r_5} = \frac{1}{4\pi \cdot 8.854 \cdot 10^{-12} \text{ F/m}} \frac{-2 \cdot 10^{-9} \text{ C}}{1 \text{ m}} = -4.5 \cdot 10^{-2} \text{ V}$$

$$V_6 = \frac{1}{4\pi\epsilon_0} \frac{q_6}{r_6} = \frac{1}{4\pi \cdot 8.854 \cdot 10^{-12} \text{ F/m}} \frac{-2 \cdot 10^{-9} \text{ C}}{1 \text{ m}} = -4.5 \cdot 10^{-2} \text{ V}$$

$$V_7 = \frac{1}{4\pi\epsilon_0} \frac{q_7}{r_7} = \frac{1}{4\pi \cdot 8.854 \cdot 10^{-12} \text{ F/m}} \frac{-2 \cdot 10^{-9} \text{ C}}{1 \text{ m}} = -4.5 \cdot 10^{-2} \text{ V}$$

$$V_8 = \frac{1}{4\pi\epsilon_0} \frac{q_8}{r_8} = \frac{1}{4\pi \cdot 8.854 \cdot 10^{-12} \text{ F/m}} \frac{-2 \cdot 10^{-9} \text{ C}}{1 \text{ m}} = -4.5 \cdot 10^{-2} \text{ V}$$

$$V_9 = \frac{1}{4\pi\epsilon_0} \frac{q_9}{r_9} = \frac{1}{4\pi \cdot 8.854 \cdot 10^{-12} \text{ F/m}} \frac{-2 \cdot 10^{-9} \text{ C}}{1 \text{ m}} = -4.5 \cdot 10^{-2} \text{ V}$$

$$V_{10} = \frac{1}{4\pi\epsilon_0} \frac{q_{10}}{r_{10}} = \frac{1}{4\pi \cdot 8.854 \cdot 10^{-12} \text{ F/m}} \frac{-2 \cdot 10^{-9} \text{ C}}{1 \text{ m}} = -4.5 \cdot 10^{-2} \text{ V}$$


1. Calculate the single forces $\vec{F}_1$, $\vec{F}_2$, $\vec{F}_3$, on the charge q_0 !

Path

First, calculate the magnitude of the forces, like F_1 .

The force F_1 is purely on the x -axis and therefore equal to

$$F_{1,x} = F_1 = \frac{1}{4\pi\epsilon_0} \frac{q_1 q_0}{r_{10}^2} = \frac{1}{4\pi \cdot 8.854 \cdot 10^{-12} \text{ F/m}} \frac{(-2 \cdot 10^{-9} \text{ C}) \cdot (-1 \cdot 10^{-9} \text{ C})}{(1 \text{ m})^2} = 4.5 \cdot 10^{-2} \text{ N}$$

$$\frac{1}{4\pi\epsilon_0} \cdot \frac{q_1 \cdot q_0}{r_{01}^2} \parallel \&= \frac{1}{4\pi \cdot 8.854 \cdot 10^{-12} \cdot \text{As/Vm}} \cdot \frac{1 \cdot 10^{-9} \cdot \text{C} \cdot 2 \cdot 10^{-9} \cdot \text{C}}{(3 \cdot 10^{-2} \cdot \text{m})^2} \parallel \&= 19.97... \cdot 10^{-6} \cdot \frac{(\text{As})^2 \cdot \text{Vm}}{\text{As} \cdot \text{m}^2} = 19.97... \cdot 10^{-6} \cdot \frac{\text{VAs}}{\text{m}} = 19.97... \cdot 10^{-6} \cdot \frac{\text{Ws}}{\text{m}} \parallel \&= 19.97... \cdot \mu\text{N} \quad \text{(to the right)} \quad \text{\end{align*}}$$

Similarly, we get for $\vec{F}_{02}$ and $\vec{F}_{03}$

$$\vec{F}_{02} = F_{02,x} \&= -28.09... \mu\text{N} \quad \text{(to the right)} \parallel \vec{F}_{03} \&= -22.47... \mu\text{N} \quad \text{(to the top left)} \parallel \text{\end{align*}}$$

For $\vec{F}_{03}$, we have to calculate the x - and y -component.

This is possible, by using the angle α between the line through q_0 and q_3 and the positive x -axis (pointing to the right).

So, α has to be between 90° and 180° . It can be calculated by:

$$\begin{aligned} \alpha &= \arctan\left(\frac{-4\text{cm}}{+2\text{cm}}\right) = \pi - 1.1071... = 180^\circ - 63.4...^\circ = 116.6...^\circ \end{aligned} \quad \text{\end{align*}}$$

Based on this, the x - and y -component is:

$$\begin{aligned} F_{03,x} &= |\vec{F}_{03}| \cdot \cos \alpha = 10.05... \mu\text{N} \quad \text{(to the left)} \parallel \\ F_{03,y} &= |\vec{F}_{03}| \cdot \sin \alpha = 20.10... \mu\text{N} \quad \text{(to the top)} \parallel \end{aligned} \quad \text{\end{align*}}$$

Exercise E3 Electrostatics II

(written test, approx. 10 % of a 120-minute written test, SS2022)

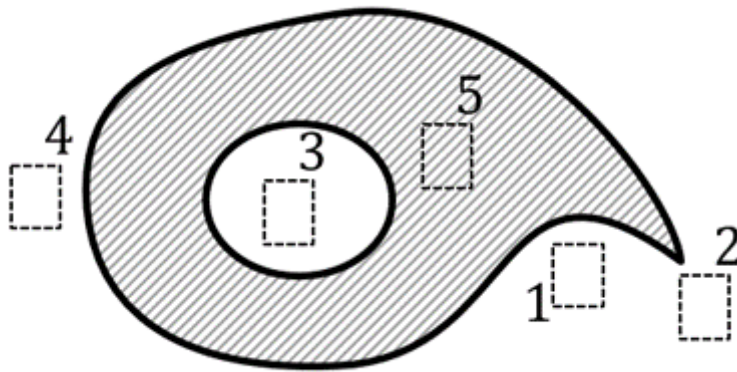
The figure below shows an arrangement of ideal metallic conductors (gray hatched) charged up to $q = +1 \text{ nC}$.

In white a dielectric (e.g. vacuum) is shown.

Several designated areas are shown by dashed frames and numbers x , which are partly inside the object.

Arrange the designated areas clearly according to ascending field strengths $|\vec{E}_x|$ (absolute magnitude)!

Indicate also, if designated areas have quantitatively the same field strength.



Result

$$|E_3| = |E_5| = 0 < |E_1| < |E_4| < |E_2|$$

Exercise E4 Electrostatics II

(written test, approx. 10 % of a 120-minute written test, SS2022)

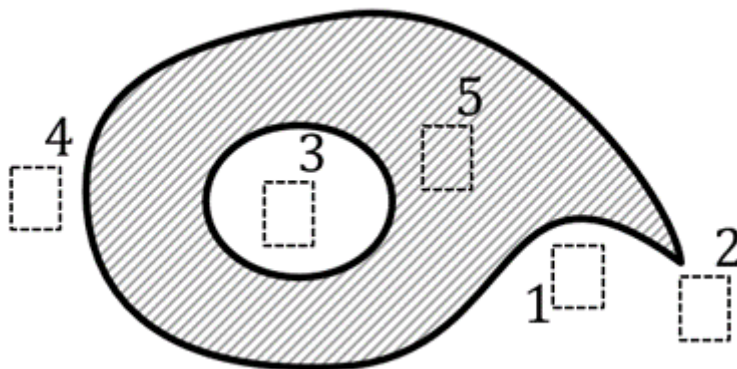
The figure below shows an arrangement of ideal metallic conductors (gray hatched) charged up to $q = +1 \text{ nC}$.

In white a dielectric (e.g. vacuum) is shown.

Several designated areas are shown by dashed frames and numbers x , which are partly inside the object.

Arrange the designated areas clearly according to ascending field strengths $|\vec{E}_x|$ (absolute magnitude)!

Indicate also, if designated areas have quantitatively the same field strength.



Result

$$|E_3| = |E_5| = 0 < |E_1| < |E_4| < |E_2|$$

Exercise E5 Electron Velocity in Semiconductors (written test, approx. 6 % of a 120-minute written test, SS2022)

A current of $I = 1 \text{ mA}$ flows through a cross-sectional area $A = 10 \text{ } \mu\text{m}^2$ in a semiconductor.

The electron density in the semiconductor is given by the number of dopant atoms per volume.

The doping shall provide 1 donor atom (= one electron) per 10^{10} silicon atoms. The elementary charge is $e = 1.602 \cdot 10^{-19} \text{ As}$ (about $41 \text{ } \mu\text{eV}$ of the speed of light). The molar volume of silicon is $V_{\text{mol,Si}} = 12 \cdot 10^{-6} \text{ m}^3/\text{mol}$, with $N_{\text{A}} = 6.022 \cdot 10^{23}$ silicon atoms per 1 mol .

The elementary charge is given as: $e = 1.602 \cdot 10^{-19} \text{ As}$

What is the average electron velocity v_e in this semiconductor?

Path

The following formula gives the speed, where n_e is the number of electrons per volume.
$$v_e = \frac{I}{n_e \cdot e \cdot A}$$

n_e can be derived from the overall number of Si-atoms per volume ($\frac{N_{\text{A}}}{V_{\text{mol,Si}}}$) and the fraction k_{Donators} of these atoms, which got substituted by donors.
$$n_e = \frac{N_{\text{A}}}{V_{\text{mol,Si}}} \cdot k_{\text{Donators}}$$

Putting in the numbers:
$$v_e = \frac{1 \cdot 10^{-3} \text{ A}}{6.022 \cdot 10^{23} \text{ 1/mol} \cdot \frac{1}{12 \cdot 10^{-6} \text{ m}^3/\text{mol}} \cdot 10^{-10} \cdot 1.602 \cdot 10^{-19} \text{ As} \cdot 10 \cdot (10^{-6} \text{ m})^2}$$

Exercise E6 Electron Velocity in Semiconductors (written test, approx. 6 % of a 120-minute written test, SS2022)

Result Current of $I = 1 \text{ mA}$ flows through a cross-sectional area $A = 10 \text{ } \mu\text{m}^2$ in a semiconductor.

The electron density in the semiconductor is given by the number of dopant atoms per volume.

The doping shall provide $5 \text{ } 10^{18} \text{ atoms/m}^3$ (about 41% of the speed of light) silicon atoms.

The molar volume of silicon is $V_{\text{mol, Si}} = 12 \cdot 10^{-6} \text{ m}^3/\text{mol}$, with $N_{\text{A}} = 6.022 \cdot 10^{23}$ silicon atoms per 1 mol .

The elementary charge is given as: $e_0 = 1.602 \cdot 10^{-19} \text{ As}$

What is the average electron velocity v_e in this semiconductor?

Path

The following formula gives the speed, where n_e is the number of electrons per volume.

$$v_e = \frac{I}{n_e \cdot e_0 \cdot A}$$

n_e can be derived from the overall number of Si-atoms per volume ($\frac{N_{\text{A}}}{V_{\text{mol, Si}}}$) and the fraction k_{Donators} of these atoms, which got substituted by donators.

$$v_e = \frac{I}{\left(\frac{N_{\text{A}}}{V_{\text{mol, Si}}} \cdot k_{\text{Donators}}\right) \cdot e_0 \cdot A}$$

Putting in the numbers:

$$v_e = \frac{1 \cdot 10^{-3} \text{ A}}{\left(\frac{6.022 \cdot 10^{23} \text{ 1/mol}}{12 \cdot 10^{-6} \text{ m}^3/\text{mol}}\right) \cdot 10^{-10} \cdot 1.602 \cdot 10^{-19} \text{ As} \cdot 10 \cdot (10^{-6} \text{ m})^2}$$

Exercise E7 Capacitor

(written test, approx. 7 % of a 120-minute written test, SS2022)

Given: The multiple capacitor in the left-side picture has the following dimensions: $\epsilon_r = 0.1 \text{ m}$

Result: ϵ_r of air ($\epsilon_r = 1$), while the thickness of the dielectric material remains the same

Path: Length of layer overlap: $l = 1.5 \text{ mm}$

Distance between single layers: $d = 1.0 \text{ } \mu\text{m}$

Depth of component: $w = 0.7 \text{ mm}$

See also: $1 \text{ mm} = 10^{-3} \text{ m}$ (from the picture): 3 left-side and 3 right-side layers.

Path

The capacity can be derived from the geometry by:

$$C = \epsilon_r \cdot \frac{A}{d}$$

The air builds another capacitor in series to the dielectric material. Therefore, the For the area A we have multiple plates with the area $A_0 = l \cdot w$ facing each other. Capacity can be calculated as

$$C_{\text{Air}} = \frac{C \cdot C_{\text{Air}}}{C + C_{\text{Air}}}$$

The capacity of air is
$$C_{\text{Air}} = \frac{\epsilon_0 \epsilon_r N \cdot l \cdot w}{d} = 8.854 \cdot 10^{-12} \cdot 3 \cdot \{5 \cdot 1.5 \cdot 10^{-3}\} \cdot \{0.7 \cdot 10^{-3}\} \cdot \{1 \cdot 10^{-6}\} = 0.465 \dots \text{ nF}$$

By this the overall capacity is
$$C_{\text{C}} = \frac{C_{\text{Air}}}{\frac{1}{0.139 \dots} + \frac{1}{0.465 \dots}} = 0.103 \dots \text{ nF}$$

How many "multiple plates" N do we have to consider?

For this, we have to count facing areas A_0 . There are $N=5$.

The material shall have a dielectric permittivity of $\epsilon_r=3$.

The following calculations shall ignore boundary effects on the end of the layers.

$\epsilon_0 = 8.854 \cdot 10^{-12} \text{ As/Vm}$

.. What is the field strength in the dielectric material between the layer, when a voltage of $U=6.3 \text{ V}$ is applied?

Path

The electric field strength E is given by:
$$E = \frac{U}{d} = \frac{6.3 \text{ V}}{1 \cdot 10^{-6} \text{ m}} = 6.3 \cdot 10^6 \text{ V/m}$$

Therefore, the formula is
$$C = \frac{\epsilon_0 \epsilon_r N \cdot l \cdot w}{d} = 8.854 \cdot 10^{-12} \cdot 3 \cdot \{5 \cdot 1.5 \cdot 10^{-3}\} \cdot \{0.7 \cdot 10^{-3}\} \cdot \{1 \cdot 10^{-6}\} = 0.465 \dots \text{ nF}$$

Exercise E8 Capacitor

(written test, approx. 7 % of a 120-minute written test, SS2022)

6. Calculate the multiple capacitance of the shown device, with the following dimensions: $\epsilon_r=3$, $\epsilon_0=8.854 \cdot 10^{-12} \text{ As/Vm}$, $U=6.3 \text{ V}$, $d=1 \cdot 10^{-6} \text{ m}$, $l=5 \cdot 10^{-3} \text{ m}$, $w=1.5 \cdot 10^{-3} \text{ m}$, $N=5$.

Result: $\epsilon_r = 1.5$, while the thickness of the dielectric material remains constant between single layers: $d = 1.0 \text{ ~}\mu\text{m}$

What is the capacity C ?

- Number of layers (as shown in the picture): 3 left-side and 3 right-side layers.

$$E = \frac{U}{d} = \frac{6.3 \text{ V}}{1.0 \cdot 10^{-6} \text{ m}} = 6.3 \cdot 10^6 \text{ V/m}$$

The capacity can be derived from the geometry by:
$$C = \frac{\epsilon_0 \epsilon_r N A}{d}$$

For the area A we have multiple plates with the area $A_0 = l \cdot w$ facing each other builds another capacitor in series to the dielectric material. Therefore, the capacity can be calculated as
$$C_{\text{Air}} = \frac{C \cdot C_{\text{Air}}}{C + C_{\text{Air}}}$$

The capacity of air is
$$C_{\text{Air}} = \frac{\epsilon_0 \epsilon_r N A}{d} = 8.854 \cdot 10^{-12} \text{ As/Vm} \cdot 1 \cdot 10^{-3} \cdot 1.5 \cdot 10^{-3} \cdot 0.7 \cdot 10^{-3} = 9.15 \cdot 10^{-18} \text{ F}$$

The material shall have a dielectric permittivity of $\epsilon_r = 1.5$

The following calculations shall ignore boundary effects on the end of the layers.

By this the overall capacity is
$$C_{\text{Air}} = \frac{C \cdot C_{\text{Air}}}{C + C_{\text{Air}}} = \frac{0.139 \cdot 10^{-12} \cdot 9.15 \cdot 10^{-18}}{0.139 \cdot 10^{-12} + 9.15 \cdot 10^{-18}} = 0.139 \cdot 10^{-12} \text{ F}$$

For this, we have to count facing areas A_0 . There are $N = 5$.

What is the field strength in the dielectric material between the layer, when a voltage of $U = 6.3 \text{ V}$ is applied?

Path

The electric field strength E is given by:
$$E = \frac{U}{d} = \frac{6.3 \text{ V}}{1 \cdot 10^{-6} \text{ m}} = 6.3 \cdot 10^6 \text{ V/m}$$

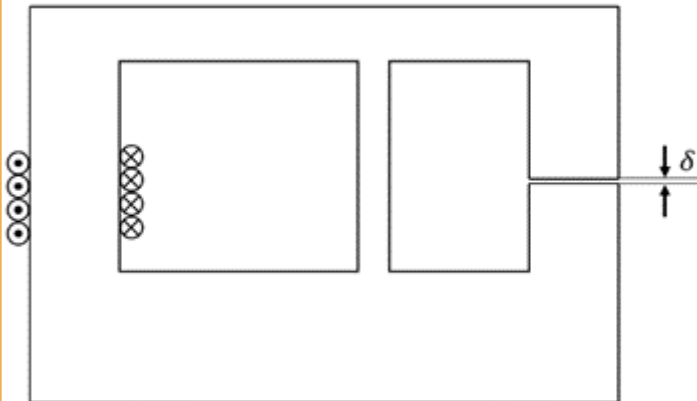
Therefore, the formula is
$$C = \frac{\epsilon_0 \epsilon_r N A}{d} = 8.854 \cdot 10^{-12} \text{ As/Vm} \cdot 3 \cdot 10^{-3} \cdot 1.5 \cdot 10^{-3} \cdot 0.7 \cdot 10^{-3} \cdot 5 \cdot 10^{-6} = 0.139 \cdot 10^{-12} \text{ F}$$

Exercise E9 Magnetic Circuit**(written test, approx. 7 % of a 120-minute written test, SS2022)**

The magnetic setup below shall be given. Draw the equivalent magnetic circuit to represent the setup fully. Name all the necessary magnetic resistances, fluxes, and voltages.

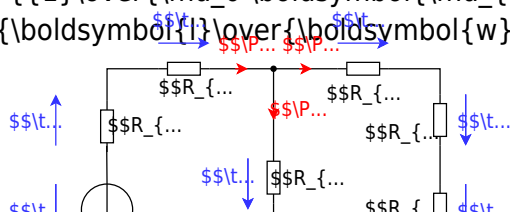
The components shall be designed in such a way, that the magnetic resistance is constant in it.

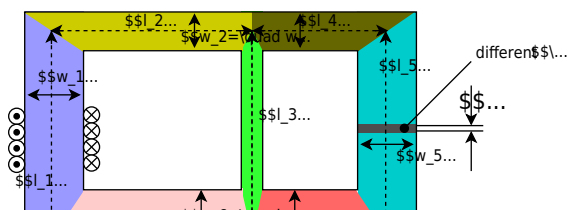
Formulas are not necessary.



Path

Watch for parts of the magnetic circuit, where the width and material are constant. These parts represent the magnetic resistors which have to be calculated individually. Be aware, that every junction creates a branch with a new resistor, like for an electrical circuit - there must be a node on each "diversion".

$$R_{\text{m}} = \frac{1}{\mu_0 \mu_{\text{r}}} \frac{l}{w \cdot h}$$




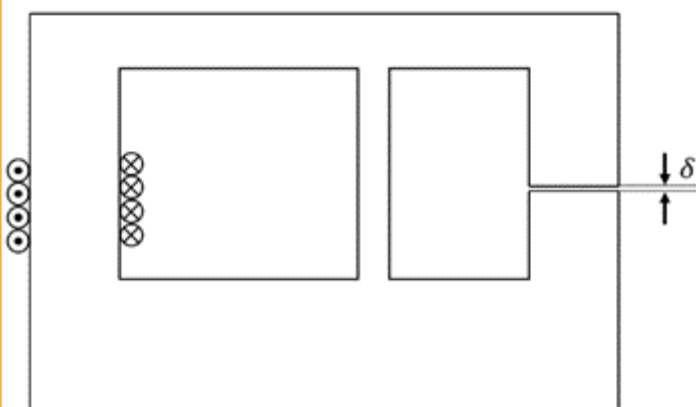
Exercise E10 Magnetic Circuit

(written test, approx. 7 % of a 120-minute written test, SS2022)

The magnetic setup below shall be given. Draw the equivalent magnetic circuit to represent the setup fully. Name all the necessary magnetic resistances, fluxes, and voltages.

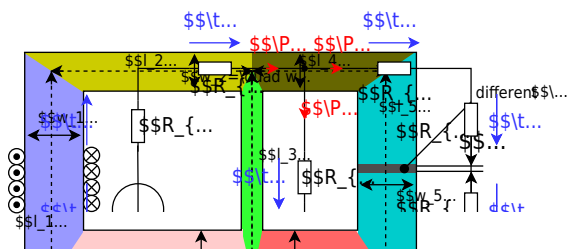
The components shall be designed in such a way, that the magnetic resistance is constant in it.

Formulas are not necessary.



Path

Watch for parts of the magnetic circuit, where the width and material are constant. These parts represent the magnetic resistors which have to be calculated individually. Be aware, that every junction creates a branch with a new resistor, like for an electrical circuit - there must be a node on each "diversion".

$$R_m = \frac{1}{\mu_0 \mu_r} \frac{l}{w \cdot h}$$


Exercise E1 Self Induction

(written test, approx. 8 % of a 120-minute written test, SS2022)

2. What is the maximum magnitude of the induced voltage, which the circuit breaker has to withstand, which is fused with a circuit breaker.

Sketch the diagram of the circuit with the current $I(t) = 0$ with the percentage value of the induced voltage linearly down to 0 A within 1 ms .

(The inner resistance of the motor shall be neglected.)

$$u_{\text{ind}}(t) = 3150 \text{ V}$$

Path

... Draw the circuit (the circuit breaker can be drawn as a switch), with all voltage and current arrows.

For the maximum voltage on the circuit breaker one has to consider the following:

Result

- external voltage of the voltage source U_{S}
- voltage $u_{\text{ind}}(t)$ induced by the change of the current

The first one is not given in the exercise, and therefore not considered here.

The induced voltage can be calculated by linearizing the following:

$$u_{\text{ind}}(t) = -L \frac{di}{dt} \rightarrow u_{\text{ind}}(t) = -L \frac{\Delta i}{\Delta t}$$

With the given details:

$$u_{\text{ind}}(t) = -L \frac{0 - I}{t_1 - t_0} = 50 \cdot 10^{-6} \text{ H} \cdot \frac{63 \text{ A}}{1 \cdot 10^{-6} \text{ s}} = 3150 \frac{\text{Vs}}{\text{A}} \cdot \frac{\text{A}}{\text{s}}$$

$u_{\text{ind}}(t) = \dots$



Exercise E11 Self Induction

(written test, approx. 8 % of a 120-minute written test, SS2022)

2. A motor with a nominal voltage of $U_N = 50 \text{ V}$, which is controlled by a DC voltage source and which is fused with a circuit breaker.

Sketch the break curve $i(t)$ and $u_{\text{ind}}(t)$ with a current $I_N = 63 \text{ A}$ of the induced current $i(t)$ linearly down to 0 A within $1 \mu\text{s}$.

(The inner resistance of the motor shall be neglected.)

$$u_{\text{ind}}(t) = 3150 \text{ V}$$

Path

.. Draw the circuit (the circuit breaker can be drawn as a switch), with all voltage and current arrows.

For the maximum voltage on the circuit breaker one has to consider the following:

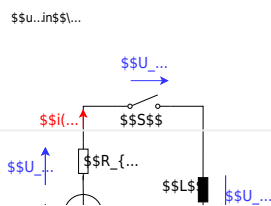
- external voltage of the voltage source U_{S}
- voltage $u_{\text{ind}}(t)$ induced by the change of the current

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The induced voltage can be calculated by linearizing the following:

$$u_{\text{ind}}(t) = -L \frac{di}{dt} \rightarrow u_{\text{ind}}(t) = -L \frac{\Delta i}{\Delta t}$$

With the given details:
$$u_{\text{ind}}(t) = -L \frac{dI}{dt} = 50 \cdot 10^{-6} \cdot \frac{63 \cdot A}{1 \cdot 10^{-6} \cdot s} = 3150 \frac{Vs}{A} \cdot \frac{A}{s}$$



Exercise E12 Series Resonant Circuit (written test, approx. 10 % of a 120-minute written test, SS2022)

2. What is the resonance frequency of the circuit shown in the diagram? What is the value of the inductance \$L\$?

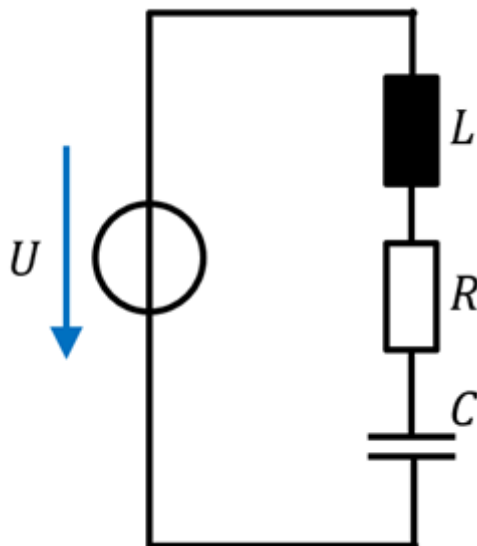
And in this case, what is the value of the capacitance \$C\$? Which value would \$C\$ have for the given \$f_0\$?

- Path 1: $C = 10 \text{ nF}$
 Path 2: $L = 88.6 \text{ mH}$
 Path 3: $f_0 = 205.5 \text{ MHz}$
 Path 4: $I = 60 \text{ mA}$

The resonance frequency is given as
$$f_r = \frac{1}{2\pi\sqrt{LC}} = \frac{1}{2\pi\sqrt{60 \cdot 10^{-12} \cdot H}} = 205.5 \text{ MHz}$$

At resonance, the impedance is given purely by the resistor.
$$Z_{RLC} = X_C = \frac{1}{2\pi f \cdot C} \Rightarrow C = \frac{1}{2\pi f \cdot Z_{RLC}}$$

With values:
$$C = \frac{1}{2\pi \cdot 100 \cdot 10^6 \cdot 10.6 \cdot 10^{-9}} = 0.1500 \text{ nF}$$



1. What is the impedance $\underline{Z}_{RLC}$ of this real capacitor for $f_0 = 100 \text{ MHz}$? (Phase and magnitude)

Path

The impedance $\underline{Z}_{RLC}$ is given by:
$$\underline{Z}_{RLC} = R + \underline{X}_L + \underline{X}_C \quad \Leftrightarrow R + j\omega L - \frac{j}{\omega C} \quad \Leftrightarrow R + j \cdot \left(\omega L - \frac{1}{\omega C} \right) \quad \Leftrightarrow R + j \cdot X_{LC}$$

Putting in the numbers, only for the reactive part X_{LC} :
$$X_{LC} = 2\pi \cdot f_0 \cdot L - \frac{1}{2\pi \cdot f_0 \cdot C} \quad \Leftrightarrow 2\pi \cdot 100 \cdot 10^6 \text{ Hz} \cdot 60 \cdot 10^{-12} \text{ H} - \frac{1}{2\pi \cdot 100 \cdot 10^6 \text{ Hz} \cdot 10 \cdot 10^{-9} \text{ F}} \quad \Leftrightarrow -121.45 \dots \text{ m}\Omega$$

With the real and imaginary parts, we can derive the magnitude and phase:
$$Z_{RLC} = \sqrt{R^2 + X_{LC}^2} \quad \Leftrightarrow \sqrt{(88 \text{ m}\Omega)^2 + (-121.45 \text{ m}\Omega)^2} \quad \Leftrightarrow 150.0 \dots \text{ m}\Omega$$

$$\varphi = \arctan \left(\frac{X_{LC}}{R} \right) \quad \Leftrightarrow \arctan \left(\frac{-121.45 \text{ m}\Omega}{88 \text{ m}\Omega} \right) \quad \Leftrightarrow -54.07 \dots^\circ$$

Exercise E13 Series Resonant Circuit**(written test, approx. 10 % of a 120-minute written test, SS2022)**

2. What is the magnitude of the RMS voltage U_{eff} for the given capacitor and inductor? Result in V (phase and magnitude). Inductance L .

At resonance, the magnitude of the impedance Z_{RLC} would be $Z_{\text{RLC}} = Z_{\text{RLC}}$.

Which value would C have for the given f_0 ?

Path: $C = 10 \text{ nF}$

$R = 88 \text{ m}\Omega$

Path: $L = 60 \text{ nH}$

$f_0 = 100 \text{ MHz}$

The resonance frequency is given as $f_{\text{r}} =$

$$\frac{1}{2\pi\sqrt{LC}} \quad \&= \quad \frac{1}{2\pi\sqrt{60 \cdot 10^{-12} \cdot C}} \quad \text{H}$$

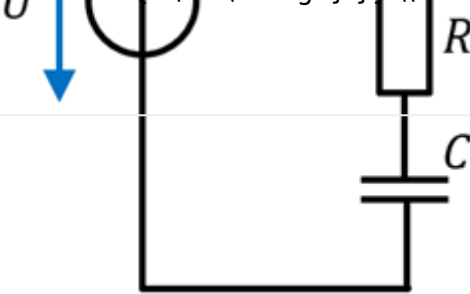
The calculated impedance $Z_{\text{RLC}} = 20.5 \text{ m}\Omega$ has to be set equal to Z_{RLC} .

$$\begin{aligned} Z_{\text{RLC}} &= \sqrt{R^2 + X_C^2} \quad \&= \quad \frac{1}{2\pi f \cdot C} \quad \rightarrow C \end{aligned}$$

At resonance the impedance Z_{RLC} is purely real.

With values: $C = \frac{1}{2\pi \cdot 100 \cdot 10^6 \cdot 20.5 \cdot 10^{-3}}$

$$C = 10.6 \text{ nF}$$



1. What is the impedance Z_{RLC} of this real capacitor for $f_0 = 100 \text{ MHz}$? (Phase and magnitude)

Path

The impedance Z_{RLC} is given by: $\begin{aligned} Z_{\text{RLC}} &= R + jX_L + jX_C \quad \&= \quad R + j\omega L - \frac{j}{\omega C} \quad \&= \quad R + j\left(\omega L - \frac{1}{\omega C}\right) \quad \&= \quad R + jX_{\text{LC}} \end{aligned}$

$$\begin{aligned} X_{\text{LC}} &= 2\pi \cdot 100 \cdot 10^6 \cdot 60 \cdot 10^{-12} - \frac{1}{2\pi \cdot 100 \cdot 10^6 \cdot 10.6 \cdot 10^{-9}} \\ &= 2\pi \cdot 100 \cdot 10^6 \cdot 60 \cdot 10^{-12} - \frac{1}{2\pi \cdot 100 \cdot 10^6 \cdot 10.6 \cdot 10^{-9}} \end{aligned}$$

Putting in the numbers, only for the reactive part X_{LC} : $\begin{aligned} X_{\text{LC}} &= 2\pi \cdot 100 \cdot 10^6 \cdot 60 \cdot 10^{-12} - \frac{1}{2\pi \cdot 100 \cdot 10^6 \cdot 10.6 \cdot 10^{-9}} \end{aligned}$

$$\begin{aligned} X_{\text{LC}} &= 2\pi \cdot 100 \cdot 10^6 \cdot 60 \cdot 10^{-12} - \frac{1}{2\pi \cdot 100 \cdot 10^6 \cdot 10.6 \cdot 10^{-9}} \\ &= 2\pi \cdot 100 \cdot 10^6 \cdot 60 \cdot 10^{-12} - \frac{1}{2\pi \cdot 100 \cdot 10^6 \cdot 10.6 \cdot 10^{-9}} \\ &= -121.45 \text{ m}\Omega \end{aligned}$$

With the real and imaginary parts, we can derive the magnitude and phase:

$$\begin{aligned} Z_{\text{RLC}} &= \sqrt{R^2 + X_{\text{LC}}^2} \quad \&= \quad \sqrt{(88 \text{ m}\Omega)^2 + (-121.45 \text{ m}\Omega)^2} \\ &= 150.0 \text{ m}\Omega \end{aligned}$$

```
\begin{align*} \varphi &= \arctan \left( \frac{X_{LC}}{R} \right) \quad \&= \arctan \\ &\left( \frac{-121.45 \sim \rm m\Omega}{88 \sim \rm m\Omega} \right) \quad \&= -0.9437... \\ &= -54.07...^\circ \end{align*}
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